TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# **TC74HC259AP, TC74HC259AF**

#### 8-Bit Addressable Latch

The TC74HC259A is a high speed CMOS ADDRESSABLE LATCH fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The respective bits are controlled by address inputs A, B, and C. When  $\overrightarrow{\text{CLEAR}}$  input is held high and enable input G is held low, the data is written into the bit selected by address inputs, the other bit hold their previous conditions.

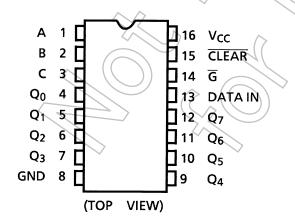
When both  $\overline{\text{CLEAR}}$  and  $\overline{\text{G}}$  held high, writing of all bits is inhibited regardless of adress inputs, and their previous condition are held. When  $\overline{\text{CLEAR}}$  is held low and  $\overline{\text{G}}$  is held high, all bits are resent to low regardless of the other inputs. When both of  $\overline{\text{CLEAR}}$  and  $\overline{\text{G}}$  held low, all bits which isn't selected by adress inputs are resent to low.

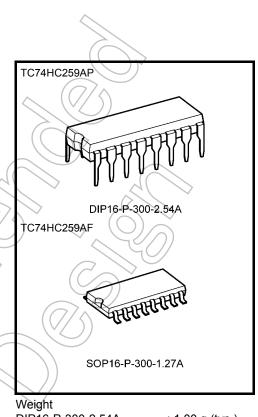
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### Features

- High speed:  $t_{pd}$  = 15 ns (typ.) at V<sub>CC</sub> = 5 V
- Low power dissipation:  $I_{CC} = 4 \ \mu A \ (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity:  $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}$  (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays: tpLH ≃ tpHL
- Wide operating voltage range: VCC (opr) = 2 to 6 V
- Pin and function compatible with 74LS259

#### **Pin Assignment**





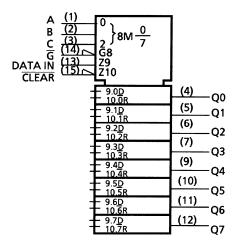
DIP16-P-300-2.54A SOP16-P-300-1.27A

: 1.00 g (typ.) : 0.18 g (typ.)

Start of commercial production 1988-05

# TOSHIBA

# **IEC Logic Symbol**



### **Truth Table**

Input	S	Output of Addressed	Each Other	Function	
CLEAR	G	Latch	Output	out	
Н	L	D	QiO	Addressable Latch	
Н	Н	QiO	QiO	Memory	
L	L	D	L	8-Line Demultriplexer	
L	Н	L	L	Clear All Bits to "L"	

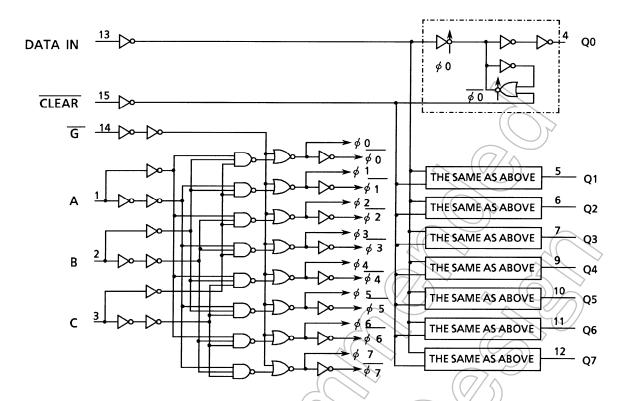
Select Inputs			Latch Addressed
С	В	А	
L	L	L	Q0 ((
L	L	Н	Q1
L	Н	L	Q2
L	Н	Н	Q3
Н	L	L	Q4
Н	L	Н	Q5
Н	Н	Ļ	Q6
Н	Н	٦.	Q7

D: The level at the data input.

QiO: The level before the indicared steady-state input conditions were established (i = 0, 1, ..., 7)

# TOSHIBA

#### System Diagram



# Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	NCC	–0.5 to 7.0	V
DC input voltage	VIN	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	Vout	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	Лк	±20	mA
Output diode current	Ioк <	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	∼ –65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied until 300 mW.

# **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2 to 6	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	Vout	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
		0 to 1000 (V <sub>CC</sub> = 2.0 V)	
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 500 (V <sub>CC</sub> = 4.5 V)	ns
		0 to 400 (V <sub>CC</sub> = 6.0 V)	$\langle \bigcirc \rangle$

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Т	est Condition		9	Ta = 25°C		-40 to	Unit	
			20	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
				2.0	1.50	)	Ľ,	1.50	_	
High-level input voltage	VIH		- 1	4.5	3.15	$(\mathcal{H})$	) - (	3.15	—	V
6			$\langle \rangle$	6.0	4.20		/_	4.20		
				2.0	`	)-	0.50	—	0.50	
Low-level input voltage	V <sub>IL</sub>	((-		4.5	$\left\langle \cdot \right\rangle$	//	1.35	—	1.35	V
			$\bigcirc$	6.0	$\rightarrow$	_	1.80	_	1.80	
		$(C \leq$		2.0	1.9	2.0	—	1.9	—	
l Bala Jacob a david			I <sub>OH</sub> = –20 μA	4.5	4.4	4.5	—	4.4	—	
High-level output voltage	V <sub>OH</sub>		4	6.0	5.9	6.0	—	5.9	—	V
			I <sub>OH</sub> = -4 mA	4.5	4.18	4.31	—	4.13	—	
			1 <sub>OH</sub> = -5.2 mA	6.0	5.68	5.80	—	5.63	_	
		_		2.0	—	0.0	0.1	—	0.1	
			l <sub>OL</sub> = 20 μA	4.5	—	0.0	0.1	—	0.1	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		6.0		0.0	0.1	_	0.1	V
	$\bigtriangledown$	$\left( \right)$	$I_{OL} = 4 \text{ mA}$	4.5	—	0.17	0.26	—	0.33	
		4	$I_{OL} = 5.2 \text{ mA}$	6.0	—	0.18	0.26	—	0.33	
Input leakage current		V <sub>IN</sub> = V <sub>CC</sub> or	GND	6.0			±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or	GND	6.0			4.0		40.0	μΑ

# Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
			V <sub>CC</sub> (V)	Тур.	Limit	Limit	
Minimum nules width			2.0	_	75	95	
Minimum pulse width $(\overline{G})$	t <sub>W (L)</sub>	—	4.5 <	_	15	19	ns
(6)			6.0		13	16	
Minimum pulse width			2.0	(£	75	95	
(CLEAR)	t <sub>W (L)</sub>	—	4.5		15	19	ns
(OLLAR)		4	6.0	$\langle \cdot \rangle$	13	16	
Minimum set-up time			2.0		50	60	
(DATA)	t <sub>s</sub>	—	(4.5)	>	10	12	ns
		G	6.0	_	9	11	
Minimum set-up time		40	2,0	—	25	30	
(A, B, C)	ts	-	4.5	— (	5	6	ns
(,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		$(\sqrt{2})$	6.0	((	)5	5	
Minimum hold time			2.0	$\langle \langle \rangle$	25	30	
(DATA)	t <sub>h</sub>	$\mathcal{A}$	4.5	7_	5	6	ns
		$\langle \langle \rangle \rangle$	6.0	$\langle \gamma \rangle$	5	5	
Minimum hold time			2.0		0	0	
(A, B, C)	t <sub>h</sub>	$\langle \langle \rangle \rangle$	4.5	) —	0	0	ns
(· ·, -, -)		d()	6.0	_	0	0	

# AC Characteristics (C<sub>L</sub> = 15 pF, V<sub>CC</sub> = 5 V, Ta = 25°C, input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time			_	4	8	ns
Propagation delay time	tpLH			15	22	ns
(DATA-Q)	t <sub>pHL</sub> <					
Propagation delay time	t <sub>pLH</sub>			21	32	ns
(A, B, C-Q)	tpHL			21	52	115
Propagation delay time	t <sub>pLH</sub>			10		
( <del>G</del> -Q)	tpĤ⊵	✓ –	_	16	28	ns
Propagation delay time	41			10	22	
(CLEAR-Q)	tpHL	_	_	13	23	ns

# AC Characteristics ( $C_L = 50 \text{ pF}$ , input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			$V_{CC}(V)$	Min	Тур.	Max	Min	Max	
	4		2.0	_	30	75	_	95	
Output transition time	t <sub>TLH</sub>		4.5	—	8 <	15	—	19	ns
	t <sub>THL</sub>		6.0	—	7	13	_	16	
Propagation delay	<b>+</b>		2.0	_	56	130	)	165	
time	t <sub>pLH</sub>	—	4.5	—	18	26	2_	33	ns
(DATA-Q)	t <sub>pHL</sub>		6.0	$\prec$	15	22	—	28	
Propagation delay	<b>+</b>		2.0	->	83	185	—	230	
time	t <sub>pLH</sub>	—	4.5	_((	25	> 37	—	46	ns
(A, B, C-Q)	t <sub>pHL</sub>		6.0		21	31		39	
Propagation delay	t <sub>pLH</sub>		2.0 <	1(- )	67	165	A	205	
time —		—	4.5	$\rightarrow$	20	33	$\geq \rightarrow$	41	ns
( <del>G</del> -Q)	t <sub>pHL</sub>		6.0	$\left( \begin{array}{c} \uparrow \end{array} \right)$	17	28	$) \rightarrow c$	35	
Propagation delay			2.0	2	52	135	Ľ4)	170	
time	t <sub>pHL</sub>	-	4.5	—	16	27	$\mathbb{S}^{\bigcirc}$	34	ns
(CLEAR -Q)		40	6.0	—	14	23	_	29	
Input capacitance	C <sub>IN</sub>	7	$\geq$	_	5	10	—	10	pF
Power dissipation capacitance	C <sub>PD</sub> (Note)		5		35	) _	_		pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

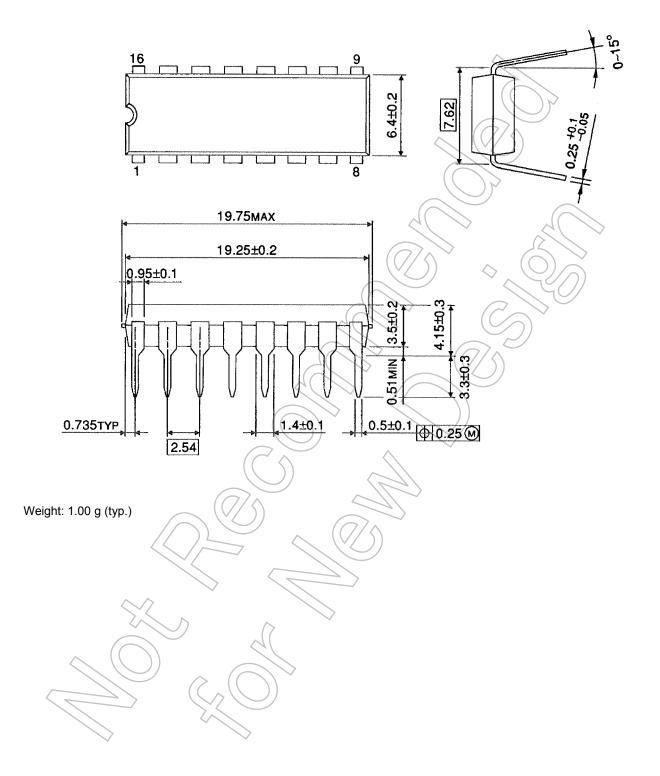
Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

#### **Package Dimensions**

DIP16-P-300-2.54A

Unit : mm

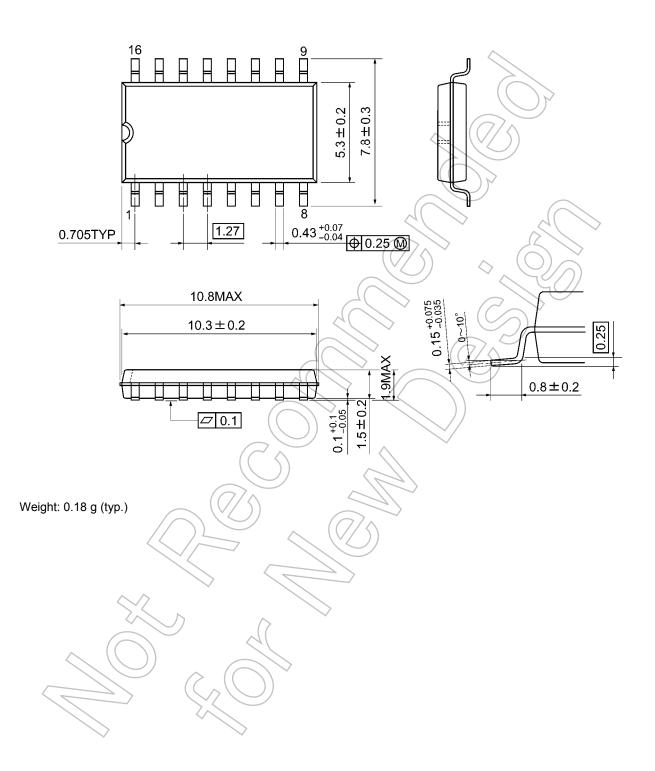




#### **Package Dimensions**

SOP16-P-300-1.27A

Unit: mm



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